



Ultrasoft Recovery Rectifier Diode

PRODUCT APPLICATIONS

- Anti-Parallel Diode

 Switchmode Power Supply
 Inverters
- Applications
 Induction Heating
- Resonant Mode Circuits

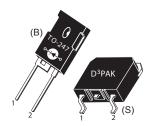
 ZVS and ZCS Topologies
 Phase Shifted Bridge

PRODUCT FEATURES

- Ultrasoft Recovery Times (t_{rr})
- Popular TO-247 Package or Surface Mount D³PAK Package
- Ultra Low Forward Voltage
- Low Leakage Current

PRODUCT BENEFITS

- Soft Switching High Q_{rr}
- Low Noise Switching
 Reduced Ringing
- · Higher Reliability Systems
- Minimizes or eliminates snubber





- 1 Cathode
- 2 Anode Back of Case - Cathode

MAXIMUM RATINGS

All Ratings: T_C = 25°C unless otherwise specified.

Symbol	Characteristic / Test Conditions	Ratings	Unit
V_R	Maximum D.C. Reverse Voltage		
V _{RRM}	Maximum Peak Repetitive Reverse Voltage	600	Volts
V _{RWM}	Maximum Working Peak Reverse Voltage		
I _{F(AV)}	Maximum Average Forward current (1) (T _C = 124°C, Duty Cycle = 0.5)	100	
I _{F(RMS)}	RMS Forward Currrent (Square wave, 50% duty)	131	Amps
I _{FSM}	Non-Repetitive Forward Surge Current (T _J = 45°C, 8.3 ms)	600	
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 to 175	°C
T _L	Lead Temperature for 10 Seconds	300	

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions		Min	Тур	Max	Unit
V _F	Forward Voltage	I _F = 100A		1.25	1.6	Volts
		I _F = 200A		2.0		
		I _F = 100A, T _J = 125°C		1.28		
I _{RM}	Maximum Reverse Leakage Current	V _R = 600V			25	- μΑ
		V _R = 600V, T _J = 125°C			250	
C _T	Junction Capacitance, V _R = 200V			97		pF

DYNAMIC CHARACTERISTICS

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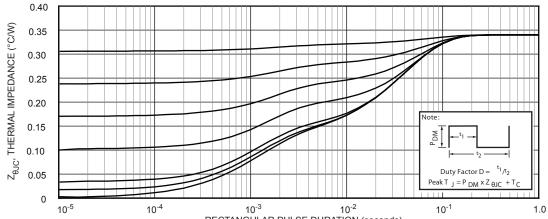
Symbol	Characteristic / Test Conditions		Min	Тур	Max	Unit
t _m	Reverse Recovery Time $I_F = 1A$, $di_F/dt = -100A/\mu s$, $V_R = 30V$, $T_J = 25$ °C			45		no
t _m	Reverse Recovery Time	I _F = 100A, di _F /dt = -200A/ μs V _R = 400V, T _C = 25°C		487		ns
Q_{rr}	Reverse Recovery Charge			2328		nC
I _{RRM}	Maximum Reverse Recovery Current			11		Amps
t _m	Reverse Recovery Time	I _F = 100A, di _F /dt = -200A/μs V _R = 400V, T _C = 125°C		716		ns
Q_{rr}	Reverse Recovery Charge			5954		nC
I _{RRM}	Maximum Reverse Recovery Current			18		Amps
t _m	Reverse Recovery Time	I _F = 100A, di _F /dt = -1000A/ μs V _R = 400V, T _C = 125°C		333		ns
Q _{rr}	Reverse Recovery Charge			10002		nC
I _{RRM}	Maximum Reverse Recovery Current			49		Amps

THERMAL AND MECHANICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	Min	Тур	Max	Unit
R _{eJC}	Junction-to-Case Thermal Resistance			0.34	°C/W
W _T	Package Weight		0.22		oz
			5.9		g
Torque	Maximum Mounting Torque			10	lb∙in
				1.1	N·m

① Continuous current limited by package lead temperature.

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RECTANGULAR PULSE DURATION (seconds)
FIGURE 1. MAXIMUM EFFECTIVE TRANSIENT THERMAL IMPEDANCE, JUNCTION-TO-CASE vs. PULSE DURATION

TYPICAL PERFORMANCE CURVES

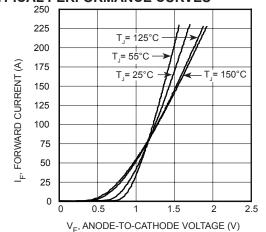


FIGURE 2, Forward Current vs. Forward Voltage

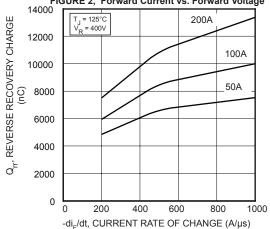
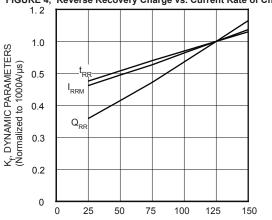


FIGURE 4, Reverse Recovery Charge vs. Current Rate of Change



 $\rm T_{\rm J},$ JUNCTION TEMPERATURE (°C) FIGURE 6, Dynamic Parameters vs Junction Temperature

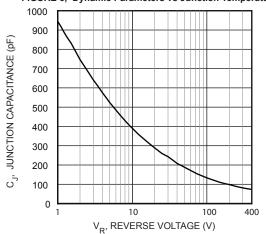


FIGURE 8, Junction Capacitance vs. Reverse Voltage

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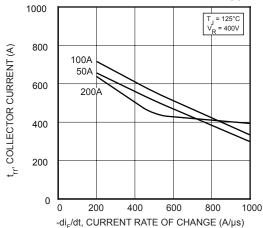


FIGURE 3, Reverse Recovery Time vs. Current Rate of Change

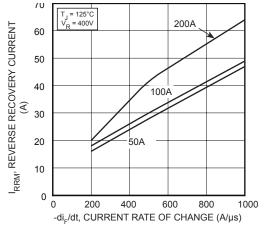


FIGURE 5, Reverse Recovery Current vs. Current Rate of Change

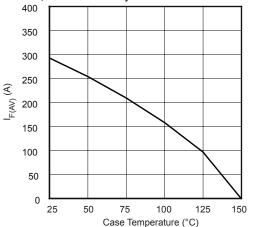


FIGURE 7, Maximum Average Forward Current vs. Case Temperature

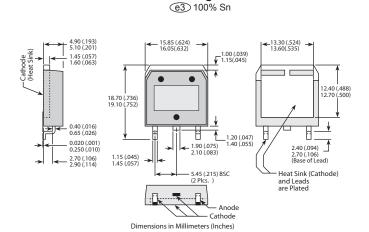
Figure 9. Diode Test Circuit

- 1 I_F Forward Conduction Current
 2 di_F/dt Rate of Diode Current Change Through Zero Crossing.
 3 I_{RRM} Maximum Reverse Recovery Current
 4 t_{rr} Reverse Recovery Time measured from zero crossing where diode current goes from positive to negative, to the point at
- which the straight line through I_{RRM} and 0.25, I_{RRM} passes through zero. Q_{rr} - Area Under the Curve Defined by I_{RRM} and t_{RR} .

Figure 10. Diode Reverse Recovery Waveform Definition

TO-247 Package Outline ©1 SAC: Tin, Silver, Copper 4.69 (185) 5.31 (209) 1.49 (059) 2.49 (098) 20.80 (819) 21.46 (845) 1.016 (.040)

Dimensions in Millimeters and (Inches)



D³PAK Package Outline

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